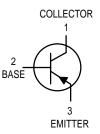
Amplifier Transistors PNP Silicon



BC307BBC307CBC308C



MAXIMUM RATINGS

Rating	Symbol	BC307, B, C	BC308C	Unit
Collector-Emitter Voltage	VCEO	-45	-25	Vdc
Collector-Base Voltage	Vсво	-50	-30	Vdc
Emitter-Base Voltage	VEBO	-5.0		Vdc
Collector Current — Continuous	IC	-100		mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	350 2.8		mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.0 8.0		Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{Stg}	-55 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	125	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (I _C = -2.0 mAdc, I _B = 0)	BC307,B,C BC308C	V(BR)CEO	-45 -25	_ _	_ _	Vdc
Emitter–Base Breakdown Voltage (I _E = –100 μAdc, I _C = 0)	BC307,B,C BC308C	V _{(BR)EBO}	-5.0 -5.0	_ _	_ _	Vdc
Collector–Emitter Leakage Current (VCES = -50 V, VBE = 0) (VCES = -30 V, VBE = 0) (VCES = -50 V, VBE = 0) TA = 125°C (VCES = -30 V, VBE = 0) TA = 125°C	BC307,B,C BC308C BC307,B,C BC308C	ICES	_ _ _ _	-0.2 -0.2 -0.2 -0.2	-15 -15 -4.0 -4.0	nAdc μA

BC307 BC307B BC307C BC308C

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS						
DC Current Gain ($I_C = -10 \mu Adc$, $V_{CE} = -5.0 Vdc$)	BC307B BC307C/308C	hFE	_ _	150 270	_ _	
$(I_{C} = -2.0 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	BC307 BC307B/308B BC307C/308C		120 200 420	— 290 500	800 460 800	
$(I_{C} = -100 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	BC307B BC307C/308C		_ _	180 300	_ _	
Collector-Emitter Saturation Voltage (I _C = -10 mAdc, I _B = -0.5 mAdc) (I _C = -10 mAdc, I _B = see Note 1) (I _C = -100 mAdc, I _B = -5.0 mAdc)		VCE(sat)	_ _ _	-0.10 -0.30 -0.25	-0.3 -0.6 -	Vdc
Base-Emitter Saturation Voltage (I _C = -10 mAdc, I _B = -0.5 mAdc) (I _C = -100 mAdc, I _B = -5.0 mAdc)		V _{BE} (sat)	_ _	-0.7 -1.0	_ _	Vdc
Base–Emitter On Voltage (I _C = -2.0 mAdc, V _{CE} = -5.0 Vdc)		VBE(on)	-0.55	-0.62	-0.7	Vdc
DYNAMIC CHARACTERISTICS		•	•	•		
Current-Gain — Bandwidth Product (I _C = -10 mAdc, V _{CE} = -5.0 Vdc, f = 100 MHz)	BC307,B,C BC308C	fT	_ _	280 320	_	MHz
Common Base Capacitance (V _{CB} = -10 Vdc, I _C = 0, f = 1.0 MHz)		C _{cbo}	_	_	6.0	pF
Noise Figure (I _C = -0.2 mAdc, V _{CE} = -5.0 Vdc, R _S = 2.0 k Ω , f = 1.0 kHz)	BC307,B,C	NF	_	2.0	10	dB
(I _C = -0.2 mAdc, V _{CE} = -5.0 Vdc, R _S = 2.0 kΩ, f = 1.0 kHz, f = 200 Hz)	BC308C		_	2.0	10	

^{1.} $I_C = -10$ mAdc on the constant base current characteristic, which yields the point $I_C = -11$ mAdc, $V_{CE} = -1.0$ V.

TYPICAL CHARACTERISTICS

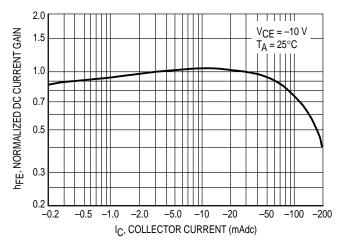


Figure 1. Normalized DC Current Gain

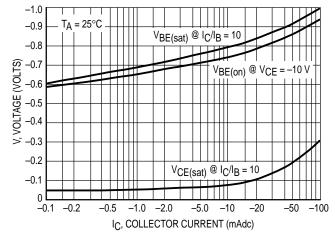


Figure 2. "Saturation" and "On" Voltages

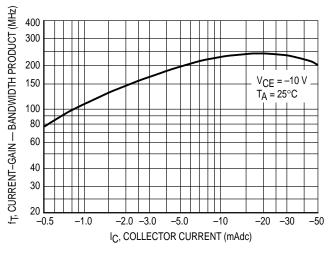


Figure 3. Current-Gain — Bandwidth Product

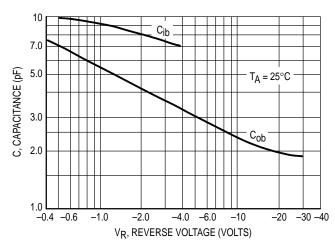


Figure 4. Capacitances

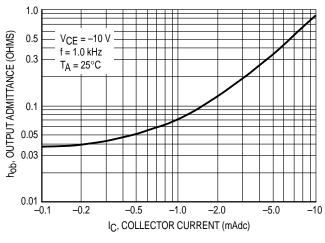


Figure 5. Output Admittance

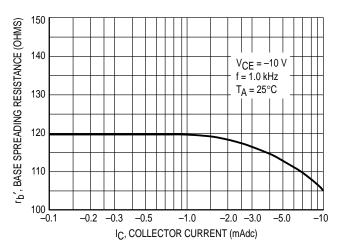
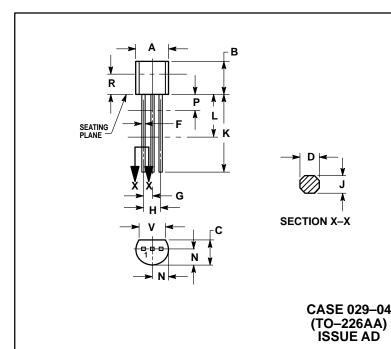


Figure 6. Base Spreading Resistance

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION P APPLIES BETWEEN P AND L.
 DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135	_	3.43		

STYLE 17: PIN 1. COLLECTOR

- 3. EMITTER

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